

# 43V Asynchronous Boost WLED Driver

## **General Description**

The RT8511A is an LED driver IC that can support up to 10 WLED in series. It is composed of a current mode boost converter integrated with a 43V/1.2A power switch running at a fixed 1MHz frequency and covering a wide VIN range from 2.7V to 24V.

The white LED current is set with an external resistor, and the feedback voltage is regulated to 200mV (typ.). During operation, the LED current can be controlled by the PWM input signal in which the duty cycle determines the feedback reference voltage.

For brightness dimming, the RT8511A is able to maintain steady control of the LED current. Therefore, no audible noises are generated on the output capacitor. The RT8511A also has programmable over voltage pin to prevent the output from exceeding absolute maximum ratings during open LED conditions. The RT8511A is available in WDFN-8L 2x2 and WDFN-8L 3x3 packages.

## **Ordering Information**

RT8511A 🗆 🗆

Package Type

QW: WDFN-8L 2x2 (W-Type) QWA: WDFN-8L 3x3 (W-Type)

Lead Plating System

G: Green (Halogen Free and Pb Free)

#### Note:

Richtek products are:

- > RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

### **Features**

• Wide Input Voltage Range: 2.7V to 24V

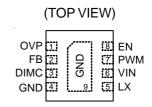
High Output Voltage: up to 43V

- Direct PWM Dimming Control and Frequency from 100Hz to 100kHz
- Internal Soft -Start and Compensation
- 200mV Reference Voltage
- PWM Dimming with Internal Filter
- Programmable Over Voltage Protection
- Over Temperature Protection
- Current Limit Protection
- Thin 8-Lead 2x2 and 8-Lead 3x3 WDFN Packages
- RoHS Compliant and Halogen Free

### **Applications**

- UMPC and Notebook Computer Backlight
- GPS, Portable DVD Backlight

## **Pin Configurations**



WDFN-8L 2x2 / WDFN-8L 3x3

# **Marking Information**

RT8511AGQW



14: Product Code W: Date Code

#### RT8511AGQWA

22=YM DNN

22=: Product Code YMDNN: Date Code



# **Typical Application Circuit**

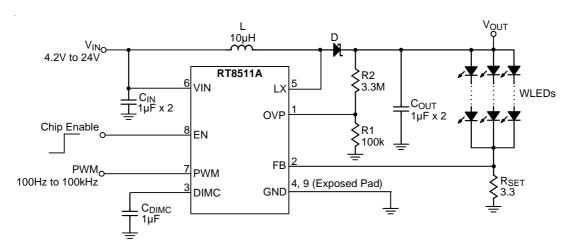


Figure 1. Typical Application Circuit of Normal Operation

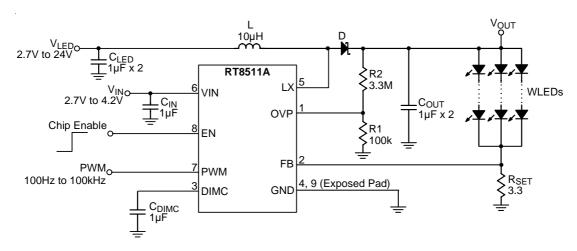


Figure 2. Typical Application Circuit of Low Voltage Operation

## **Functional Pin Description**

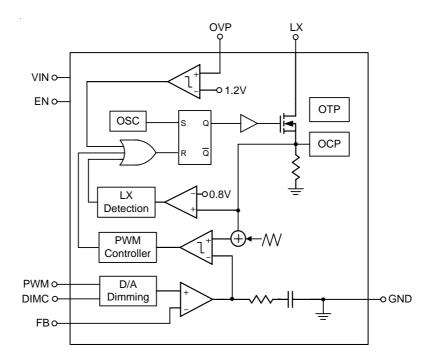
Pin No.	Pin Name	Pin Function
1	OVP	Over Voltage Protection for Boost Converter. The detecting threshold is 1.2V.
2	FB	Feedback Pin. Connect a resistor between this pin and GND to set the LED current.
3	DIMC	PWM Filter Pin. Filter the PWM signal to a DC voltage.
4	GND	Ground Pin.
5	LX	Switch Node for Boost Converter.
6	VIN	Power Supply Input.
7	PWM	Dimming Control Input.
8	EN	Chip Enable (Active High) for Boost Converter.
9 (Exposed Pad)	GND	The exposed pad must be soldered to a large PCB and connected to AGND for maximum power dissipation.

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# **Function Block Diagram**





## **Absolute Maximum Ratings** (Note 1)

• VIN, EN, PWM, DIMC to GND	-0.3V to 26.5V
• LX, FB, OVP to GND	-0.3V to 48V
<ul> <li>Power Dissipation, P<sub>D</sub> @ T<sub>A</sub> = 25°C</li> </ul>	
WDFN-8L 2x2	0.833W
WDFN-8L 3x3	1.429W
Package Thermal Resistance (Note 2)	
WDFN-8L 2x2, $\theta_{JA}$	120°C/W
WDFN-8L 2x2, $\theta_{JC}$	8.2°C/W
WDFN-8L 3x3, $\theta_{JA}$	70°C/W
WDFN-8L 3x3, $\theta_{JC}$	8.2°C/W
• Lead Temperature (Soldering, 10 sec.)	260°C
• Junction Temperature	150°C
Storage Temperature Range	–65°C to 150°C
ESD Susceptibility (Note 3)	
HBM (Human Body Model)	2kV
MM (Machine Model)	200V
December ded Operation Conditions (v)	

#### 

### **Electrical Characteristics**

( $V_{IN} = 4.5V$ ,  $T_A = 25$ °C, unless otherwise specified)

Parameter		Symbol	Test Conditions	Min	Тур	Max	Unit
VIN Quiescent Current		IQ	V <sub>FB</sub> = 1.5V, No Switching		725	-	μΑ
		IQ_SW	V <sub>FB</sub> = 0V, Switching			2.2	mA
VIN Shutdown Current		ISHDN	V <sub>IN</sub> = 4.5V, V <sub>EN</sub> = 0V		1	4	μΑ
Control Input							
EN, PWM	Logic-High	VIH	V <sub>IN</sub> = 2.7V to 24V	2			V
Threshold Voltage	Logic- Low	V <sub>IL</sub>	V <sub>IN</sub> = 2.7V to 24V			0.8	V
EN Sink Current		I <sub>IH</sub>	V <sub>EN</sub> = 3V	1		10	μΑ
Shutdown Delay		tshdn	EN high to low	26	32	40	ms
PWM Dimming Frequency				0.1		100	kHz
Boost Converter							
Switching Frequency		fosc	V <sub>IN</sub> = 2.7V to 24V	0.8	1	1.2	MHz
LX On Resistance (N-MOSFET)		R <sub>DS(ON)</sub>	V <sub>IN</sub> > 5V		0.4	0.6	Ω
Minimum ON Time					100	-	ns
Maximum Duty Cycle		D <sub>MAX</sub>	V <sub>FB</sub> = 0V, Switching		92		%

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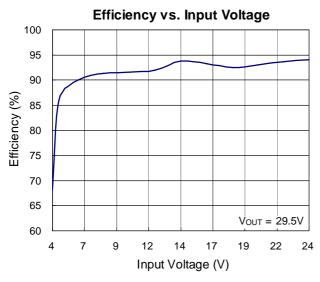


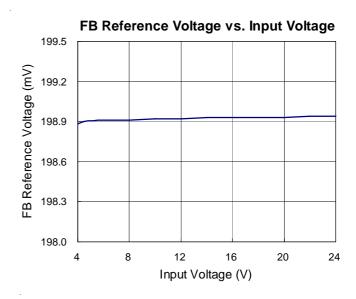
Parameter	Parameter Symbol Test Conditions		Min	Тур	Max	Unit
LED Current						
Minimum PWM Dimming Duty Cycle	D <sub>MIN</sub>	Dimming Freq. = 100Hz to 100kHz	1			%
Feedback Voltage	$V_{FB}$			200		mV
Fault Protection						
LX Current Limit	I <sub>LIM</sub>			1.2		Α
Over Voltage Protection Threshold	V <sub>OVP</sub>			1.2		V
Thermal Shutdown Temperature	T <sub>SD</sub>			160		°C
Thermal Shutdown Hysteresis	$\Delta T_{SD}$			30		°C

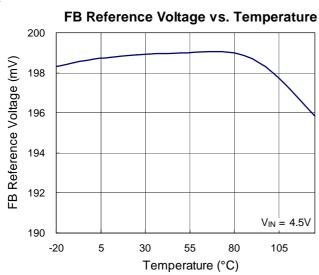
- **Note 1.** Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.
- Note 2.  $\theta_{JA}$  is measured at  $T_A = 25^{\circ}C$  on a high effective thermal conductivity four-layer test board per JEDEC 51-7.  $\theta_{JC}$  is measured at the exposed pad of the package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

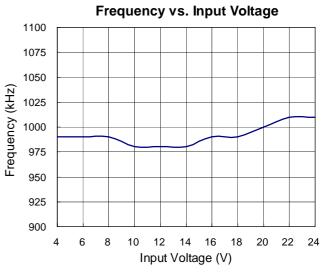


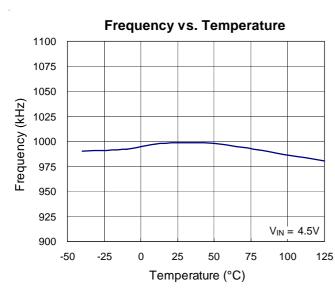
# **Typical Operating Characteristics**

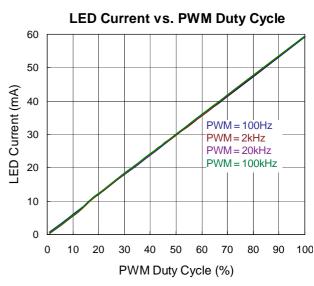














## **Application Information**

The RT8511A is a current mode boost converter which operates at a fixed frequency of 1MHz. It is capable of driving up to 10 white LEDs in series and integrates functions such as soft-start, compensation, and internal analog dimming control. The protection block also provides over-voltage, over-temperature, and current-limit protection features.

#### **LED Current Setting**

The loop structure of the boost converter keeps the FB pin voltage equal to the reference voltage  $V_{FB}$ . Therefore, by connecting the resistor,  $R_{SET}$  between the FB pin and GND, the LED current will be determined by the current through  $R_{SET}$ . The LED current can be calculated by the following equation :

$$I_{LED} = \frac{V_{FB}}{R_{SFT}}$$

### **Brightness Control**

For the brightness dimming control of the RT8511A, the IC provides typically 200mV reference voltage when the PWM pin is constantly pulled high. However, the PWM pin allows a PWM signal to adjust the reference voltage by changing the PWM duty cycle to achieve LED brightness dimming control. The relationship between the duty cycle and the FB voltage can be calculated according to the following equation:

$$V_{FB} = 200 \text{mV} \times \text{Duty}$$

where 200mV is the typical internal reference voltage and Duty is the duty cycle of the PWM signal.

As shown in Figure 3, the duty cycle of the PWM signal is used to modify the internal 200mV reference voltage. With an on-chip output clamping amplifier and a serial resistor, the PWM dimming signal is easily low-pass filtered to an analog dimming signal with one external capacitor, C<sub>DIMC</sub>, for noise-free PWM dimming. Dimming frequency can be sufficiently adjusted from 100Hz to 100kHz. However, the LED current cannot be 100% proportional to the duty cycle. Referring to Table 1, the minimum dimming duty can be as low as 1% for the frequency range from 100Hz to 100kHz. It should be noted that the accuracy of 1% duty is not guaranteed.

Because the voltage of DIMC and FB is small to 2mV and easily affected by LX switching noise.

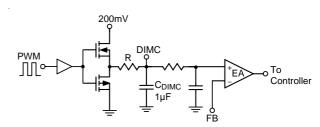


Figure 3. Block Diagram of Programmable FB Voltage.

**Table 1. Minimum Duty for Dimming Frequency** 

Dimming Frequency	Minimum Duty Cycle		
100Hz to 100kHz	1%		

It also should be noted that when the input voltage is too close to the output voltage [( $V_{OUT}-V_{IN}$ ) < 6V], excessive audible noise may occur. Additionally, for accurate brightness dimming control, the input voltage should be kept lower than the LEDs' turn on voltage.

#### Soft-Start

The RT8511A provides a built-in soft-start function to limit the inrush current, while allowing for an increased PWM frequency for dimming.

#### **Current Limiting Protection**

The RT8511A can limit the peak current to achieve over current protection. The IC senses the inductor current through the LX pin in the charging period. When the value exceeds the current limiting threshold, the internal N-MOSFET will be turned off. In the off period, the inductor current will descend. The internal MOSFET is turned on by the oscillator during the beginning of the next cycle.

In addition, the LX current limit threshold is about 0.8V.

If the voltage of LX is over 0.8V, and the fault signal accumulates 3 times with  $32\mu s$ , the MOSFET will be latched off.

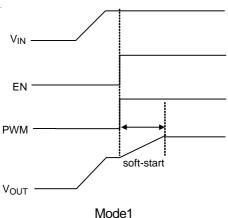
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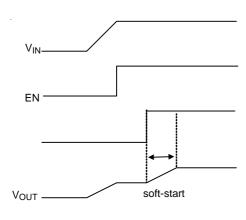
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#### **Power Sequence**

In order to assure that the normal soft start function is in place for suppressing the inrush current, the input voltage and enable voltage should be ready before PWM pulls high.





Mode2

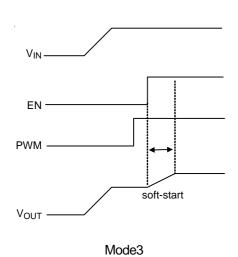
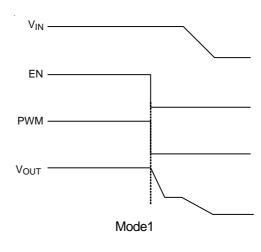
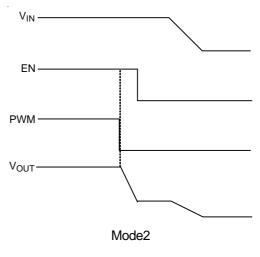


Figure 4. Power On Sequence

Figure 4 and Figure 5 show the power on and power off sequences.





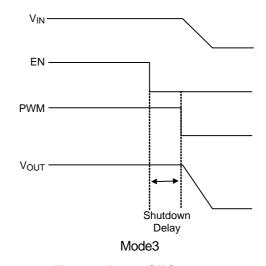


Figure 5. Power Off Sequence



#### **Over Voltage Protection**

The RT8511A equips over voltage protection (OVP) function. When the voltage at the OVP pin reaches a threshold of approximately 1.2V, the MOSFET drive output will turn off. The MOSFET drive output will turn on again once the voltage at the OVP pin drops below the threshold. Thus, the output voltage can be clamped at a certain voltage level, as shown in the following equation:

$$V_{OUT, OVP} = V_{OVP} \times \left(1 + \frac{R2}{R1}\right)$$

where R1 and R2 make up the voltage divider connected to the OVP pin.

#### **Over Temperature Protection**

The RT8511A has an over temperature protection (OTP) function to prevent overheating caused by excessive power dissipation from overheating the device. The OTP will shut down switching operation if the junction temperature exceeds 160°C. The boost converter will start switching again when the junction temperature is cooled down by approximately 30°C.

#### Inductor Selection

The inductance depends on the maximum input current. As a general rule, the inductor ripple current range is 20% to 40% of the maximum input current. If 40% is selected as an example, the inductor ripple current can be calculated according to the following equation:

$$I_{IN(MAX)} = \frac{V_{OUT} \times I_{OUT}}{\eta_{(MIN)} \times V_{IN(MIN)}}$$

$$I_{RIPPLE} = 0.4 \times I_{IN(MAX)}$$

where  $\eta$  is the efficiency of the boost converter,  $I_{IN(MAX)}$  is the maximum input current, I<sub>OUT</sub> is the total current from all LED strings, and IRIPPLE is the inductor ripple current. The input peak current can be calculated by maximum input current plus half of inductor ripple current shown as following equation:

$$I_{PEAK} = 1.2 \times I_{IN(MAX)}$$

Note that the saturated current of the inductor must be greater than IPEAK. The inductance can eventually be determined according to the following equation:

$$L = \frac{\eta \times (V_{IN})^2 \times (V_{OUT} - V_{IN})}{0.4 \times (V_{OUT})^2 \times I_{OUT} \times f_{OSC}}$$

where f<sub>OSC</sub> is the switching frequency. For better efficiency, it is suggested to choose an inductor with small series resistance.

#### **Diode Selection**

The Schottky diode is a good choice for an asynchronous boost converter due to its small forward voltage. However, when selecting a Schottky diode, important parameters such as power dissipation, reverse voltgae rating, and pulsating peak current must all be taken into consideration. A suitable Schottky diode's reverse voltage rating must be greater than the maximum output voltage, and its average current rating must exceed the average output current.

#### **Capacitor Selection**

Two 1μF ceramic input capacitors and two 1μF ceramic output capacitors are recommended for driving 10 WLEDs in series. For better voltage filtering, ceramic capacitors with low ESR are recommended. Note that the X5R and X7R types are suitable because of their wide voltage and temperature ranges.

#### **Thermal Considerations**

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where T<sub>J(MAX)</sub> is the maximum junction temperature, T<sub>A</sub> is the ambient temperature, and  $\theta_{JA}$  is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance,  $\theta_{JA}$ , is layout dependent. For WDFN-8L 2x2 packages, the thermal resistance,  $\theta_{JA}$ , is 120°C/W on a standard JEDEC 51-7 four-layer thermal test board. For WDFN-8L 3x3 packages, the thermal resistance, θ<sub>JA</sub>, is 70°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power

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dissipation at T<sub>A</sub>= 25°C can be calculated by the following formulas:

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (120^{\circ}C/W) = 0.833W$  for WDFN-8L 2X2 package

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (70^{\circ}C/W) = 1.429W$  for WDFN-8L3X3 package

The maximum power dissipation depends on operating ambient temperature for fixed T<sub>J(MAX)</sub> and thermal resistance,  $\theta_{JA}$ . The derating curves in Figure 6 allow the designer to see the effect of rising ambient temperature on the maximum power dissipation.

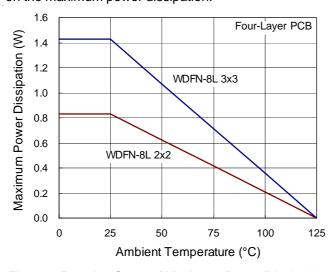


Figure 6. Derating Curve of Maximum Power Dissipation

#### **Layout Consideration**

For high frequency switching power supplies, the PCB layout is important to obtain good regulation, high efficiency and stability. The following descriptions are the suggestions for better PCB layout.

- Input and output capacitors should be placed close to the IC and connected to the ground plane to reduce noise coupling.
- > The GND and Exposed Pad should be connected to a strong ground plane for heat sinking and noise protection.
- ▶ The components L, D, C<sub>IN</sub> and C<sub>OUT</sub> must be placed as close as possible to reduce current loop. Keep the main current traces as possible as short and wide.
- ▶ The LX node of the DC/DC converter experiences is with high frequency voltage swings. It should be kept in a small area.
- The component R<sub>SET</sub> should be placed as close as possible to the IC and kept away from noisy devices.

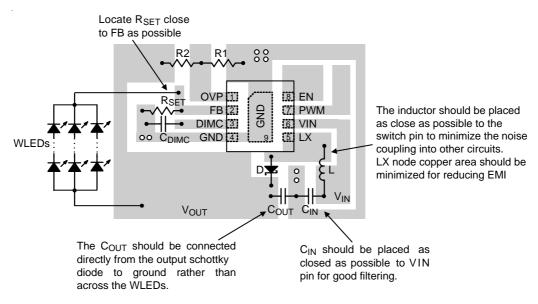
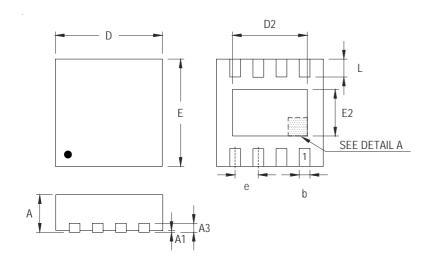
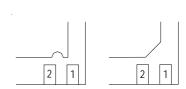


Figure 7. PCB Layout Guide



## **Outline Dimension**





<u>DETAIL A</u>

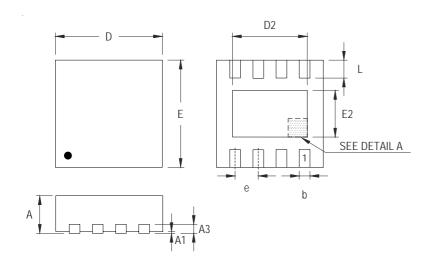
Pin #1 ID and Tie Bar Mark Options

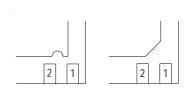
Note: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
А	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.200	0.300	0.008	0.012	
D	1.950	2.050	0.077	0.081	
D2	1.000	1.250	0.039	0.049	
Е	1.950	2.050	0.077	0.081	
E2	0.400	0.650	0.016	0.026	
е	0.5	500	0.020		
L	0.300	0.400	0.012	0.016	

W-Type 8L DFN 2x2 Package







<u>DETAIL A</u>

Pin #1 ID and Tie Bar Mark Options

Note: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Complete	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.200	0.300	0.008	0.012	
D	2.950	3.050	0.116	0.120	
D2	2.100	2.350	0.083	0.093	
Е	2.950	3.050	0.116	0.120	
E2	1.350	1.600	0.053	0.063	
е	0.650		0.026		
L	0.425	0.525	0.017	0.021	

W-Type 8L DFN 3x3 Package

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